NSN 5962-01-136-6623

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-136-6623 **Body Length:** 0.760 inches **Body Width:** 0.270 inches **Body Height:** 0.150 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** B-52g/h wst e/i fscm 36378 **Features Provided:** Hermetically sealed and monolithic and bipolar and high speed and positive outputs and schottky and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom **Memory Capacity:** Unknown **Test Data Document:** 98747-7783179 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

NSN 5962-01-136-6623

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0